



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Silicon Bridge Rectifier

 $V_{RRM} = 50\text{ V} - 1000\text{ V}$
 $I_F = 2\text{ A}$

Features

- Types up to 1000 V V_{RRM}
- Ideal for printed circuit board
- Built-in printed circuit board stand-offs
- High temperature soldering guaranteed 265°C/ 10 seconds
- High case dielectric strength
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0

KBP Package

Mechanical Data

Case: Reliable low cost construction

Weight: 0.065 oz, 2.2 g

Mounting position: Any

Terminals: Plated leads, solderable per MIL-STD-202, Method 208



Maximum ratings, at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	KBP206	KBP208	KBP210	Unit
Repetitive peak reverse voltage	V_{RRM}		600	800	1000	V
RMS reverse voltage	V_{RMS}		420	560	700	V
DC blocking voltage	V_{DC}		600	800	1000	V
Continuous forward current	I_F	$T_C \leq 50\text{ °C}$	2	2	2	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ °C}$, $t_p = 8.3\text{ ms}$	60	60	60	A
Operating temperature	T_j		-50 to 150	-50 to 150	-50 to 150	°C
Storage temperature	T_{stg}		-50 to 150	-50 to 150	-50 to 150	°C

Electrical characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	KBP206	KBP208	KBP210	Unit
Diode forward voltage	V_F	$I_F = 2\text{ A}$, $T_j = 25\text{ °C}$	1.1	1.1	1.1	V
Reverse current	I_R	$V_R = 50\text{ V}$, $T_j = 25\text{ °C}$ $V_R = 50\text{ V}$, $T_j = 100\text{ °C}$	10 200	10 200	10 200	μA

Thermal characteristics

Parameter	Symbol	Conditions	KBP206	KBP208	KBP210	Unit
Thermal resistance, junction - case	R_{thJL}		25.0	25.0	25.0	°C/W

